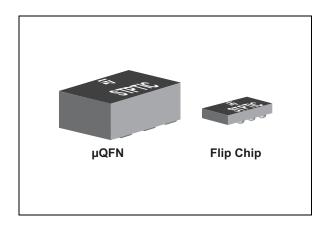




Parascan[™] tunable integrated capacitor

Datasheet - production data



Features

- High power capability (+36 dBm)
- High tuning range (3.5/1)
- High quality factor (Q)
- High linearity device
- Low leakage current
- Capacitor bias is DC blocked
- Frequency of operation from DC to 3 GHz
- 8 values available: 1.2 pF, 2.7 pF, 3.3 pF, 3.9 pF, 4.7 pF, 5.6 pF, 6.8 pF and 8.2 pF
- Analog control voltage
- Compatible with high voltage control IC (STHVDAC series)
- · Available in plastic molded package:
 - μQFN package 1.2 x 1.6 x 0.9 mm
 - Flip Chip 0.65 x 1.0 x 0.3 mm
 - Flip Chip 0.65 x 1.2 x 0.3 mm
- ECOPACK[®]2 compliant component

Benefit

 RF tunable passive implementation in mobile phones to optimize antenna radiated performances.

Applications

- Cellular Antenna open loop tunable matching network in multi-band GSM/WCDMA/LTE mobile phone
- · Open loop tunable RF filters

Description

The ST integrated tunable capacitor, offers excellent RF performance, low power consumption and high linearity required in adaptive RF tuning applications. The fundamental building block of PTIC is a tunable material called Parascan, which is a version of barium strontium titanate (BST) developed by Paratek microwave.

BST capacitances are tunable capacitances intended for use in mobile phone application, and dedicated to RF tunable applications. These tunable capacitances are controlled through a bias voltage ranging from 2 to 20 V. The use of BST tunable capacitance in mobile phones enables significant improvement in terms of radiated performances making the performance almost insensitive to the external environment.

TM: Parascan is a trade mark of Paratek microwave Inc.

Functional characteristics 1

DC Bias NC RF1 RF2 RF2 RF1

Figure 1. PTIC functional block diagram

Table 1. Signal descriptions

	Ball/Pad number	Pin name	Description
	A1	DC BIAS	DC bias voltage
Obsole	B1	RF2	RF input / output
	C1	RF2	RF input / output
	A2	NC	Not connected
	B2	RF1	RF input / output
	C2	RF1	RF input / output

2 Electrical characteristics

Table 2. Absolute maximum ratings (limiting values)

Symbol	Parameter	Rating	Unit	
P _{IN}	Input peak power RF _{IN} (CW mode)/all RF ports	+36	dBm	
		STPTIC-12	500	V
		STPTIC-27	400 ⁽¹⁾	
		STPTIC-33	400 ⁽¹⁾	
V _{ESD(HBM)}	Human body model, JESD22-A114-B, all I/O	STPTIC-39	500	
		STPTIC-47	500	
		STPTIC-56	500	
		STPTIC-68	500	
		STPTIC-82	500	
V _{ESD(MM)}	Machine model, JESD22-A114-B, all I/O	100	V	
T _{device}	Device temperature	+125	°C	
T _{stg}	Storage temperature	-55 to +150		
V _x	Bias voltage		25	V

^{1.} Currently failing around 400 V, improvement on going to withstand 500 V on 2p7 and 3p3.

Table 3. Recommended operating conditions

	Symbol	Parameter		Rating		
Symbol		1 arameter		Тур.	Max.	Unit
Obsole	Pin	RF input power (50% duty cycle mode) RF _{IN} (LB) RF _{IN} (HB)			+35 +33	dBm
	F _{OP}	Operating frequency	700		3000	MHz
	T _{device}	Device temperature			+100	°C
	T _{OP}	Operating temperature	-30		+85	
	V _x	Bias voltage	2		20	V

Electrical characteristics STPTIC

Table 4. Representative performances (T_{amb} = 25 °C)

O	Parameter	On divisor	Value			1111
Symbol		Conditions	Min	Тур	Max	Unit
		STPTIC-12	1.08	1.20	1.32	pF
		STPTIC-27	2.43	2.7	2.97	pF
		STPTIC-33	2.97	3.3	3.63	pF
	Capacitance at 2V bias	STPTIC-39	3.51	3.9	4.29	pF
C _{2V}	Capacitatice at 2 v bias	STPTIC-47	4.23	4.7	5.17	pF
		STPTIC-56	5.04	5.6	6.16	pF
		STPTIC-68	6.12	6.8	7.48	pF
		STPTIC-82	7.38	8.2	9.02	
ΙL	Leakage current	Measured with V _{bias} = 20 V		0,	100	nA
ΔС	Tuning range	Ratio between C _{2V} /C _{20V} measured at 100 kHz	3/1	3.5/1		
Q _{LB}	Quality factor	Measured at 900 MHz		65		
Q _{HB}	Quality factor	Measured at 1800 MHz		45		
IP3	Third and an intercent point	$V_{bias} = 2 V^{(1)}$ and $^{(3)}$		60		dBm
IFS	Third order intercept point	V _{bias} = 20 V ⁽¹⁾ and ⁽³⁾		70		dBm
ПО	Second harmonic	$V_{bias} = 2 V^{(2)} \text{ and } ^{(3)}$		-65		dBm
H2		V _{bias} = 20 V ⁽²⁾ and ⁽³⁾		-65		dBm
НЗ	Third harmonic	$V_{bias} = 2 V^{(2)} \text{ and } ^{(3)}$		-45		dBm
	THIIG HATHIUTIC	V _{bias} = 20 V ⁽²⁾ and ⁽³⁾		-45		dBm
.0	Transition time	From C _{min} to C _{max} ⁽⁴⁾		135		μs
t _T	Transition time	From C _{max} to C _{min} ⁽⁴⁾		100		μs

^{1.} $F_1 = 894$ MHz, $F_2 = 849$ MHz, $P_1 = 20$ dBm, $P_2 = -15$ dBm, $2f_1 - f_2 = 939$ MHz

^{2. 894} MHz, P_{in} = 34 dBm

^{3.} IP3 and harmonics are measured in the shunt/series configuration in a 50 Ω environment

^{4.} One or both of $\mathrm{RF}_{\mathrm{in}}$ and $\mathrm{RF}_{\mathrm{out}}$ must be connected to DC ground

3 Package information

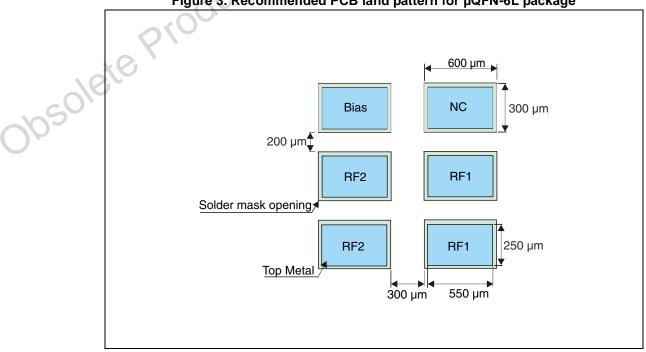
- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

1.2 mm ± 0.05 mm 0.7 mm .6 mm ± 0.05 mm (A2) (A1) 0.5 mm (B1) B2 C2 C1 0.25 mm ± 0.03 mm 0.425 mm 0.35 mm 0.9 mm ± 0.03 mm ± 0.1 mm

Figure 2. µQFN-6L package dimension





Package information STPTIC

Figure 4. Flip Chip dimensions (size for 1p5)

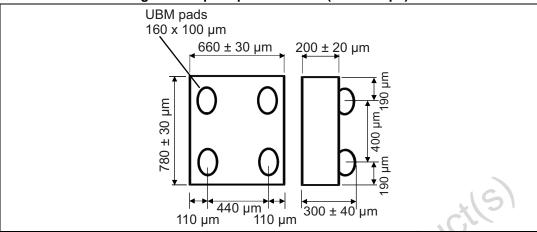


Figure 5. Flip Chip dimensions (size for 2p7, 3p3, 3p9, and 4p7)

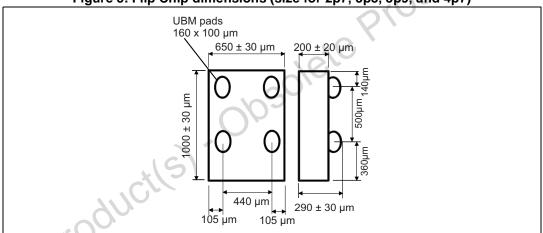
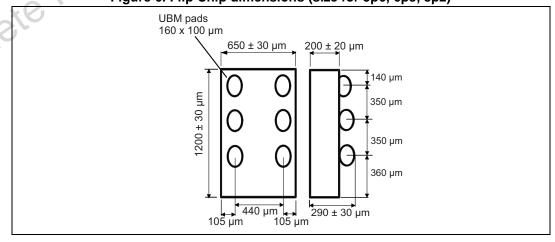


Figure 6. Flip Chip dimensions (size for 5p6, 6p8, 8p2)



47/

STPTIC Package information

Figure 7. Recommended PCB land pattern for Flip Chip package (metal defined pads, solder mask 25 µm larger)

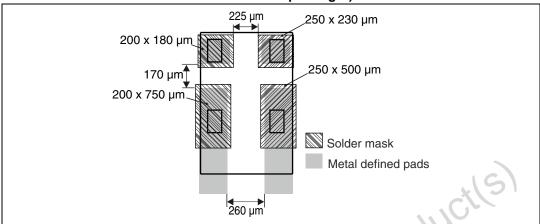
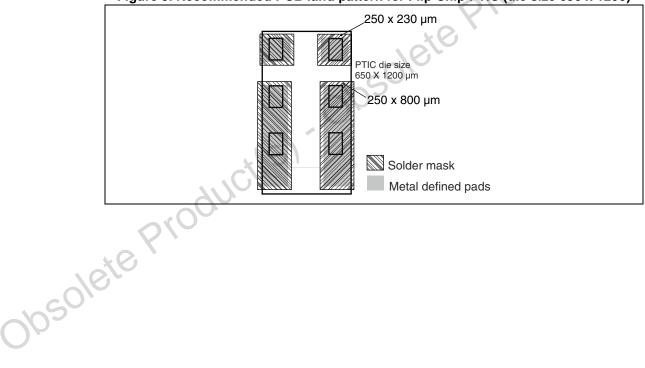


Figure 8. Recommended PCB land pattern for Flip Chip PTIC (die size 650 x 1200)



Package information STPTIC

Dot identifying bump A1 location

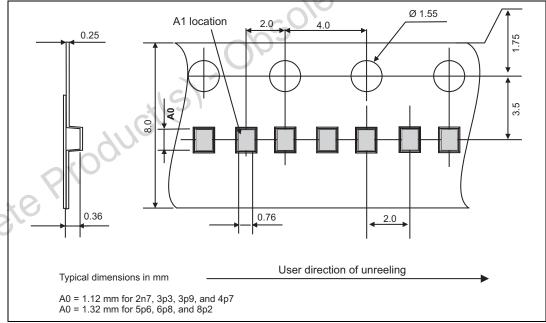
0.25

1.05

User direction of unreeling

Figure 9. µQFN-6L tape and reel specification







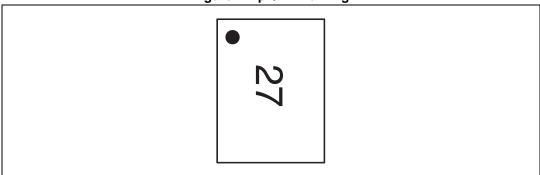
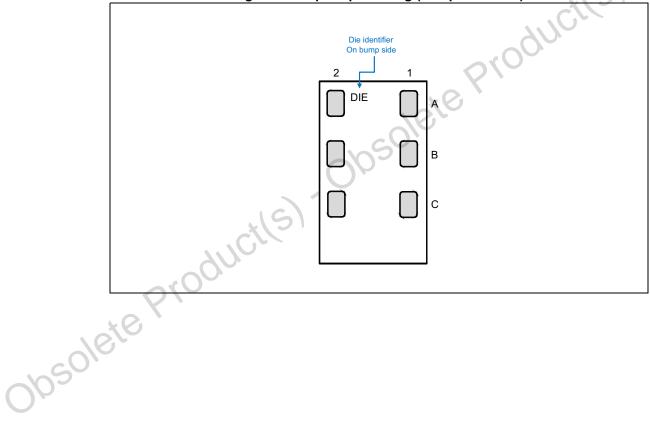
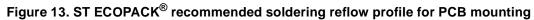


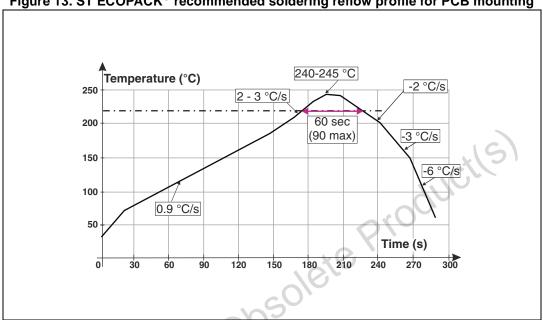
Figure 12. Flip Chip marking (bump side view)



Reflow profile STPTIC

4 Reflow profile





Note: Minimize air convection currents in the reflow oven to avoid component movement.

Table 5. Recommended values for soldering reflow

Du Ell	Value		
Profile	Typical	Max.	
Temperature gradient in preheat (T = 70-180 °C)	0.9 °C/s	3 °C/s	
Temperature gradient (T = 200-225 °C)	2 °C/s	3 °C/s	
Peak temperature in reflow	240-245 °C	260 °C	
Time above 220 °C	60 s	90 s	
Temperature gradient in cooling	-2 to -3 °C/s	-6 °C/s	
Time from 50 to 220 °C	160 to	220 s	
	Temperature gradient (T = 200-225 °C) Peak temperature in reflow Time above 220 °C Temperature gradient in cooling	Profile Typical Temperature gradient in preheat (T = 70-180 °C) Temperature gradient (T = 200-225 °C) Peak temperature in reflow 240-245 °C Time above 220 °C Temperature gradient in cooling -2 to -3 °C/s	

STPTIC Ordering information

5 Ordering information

Figure 14. Ordering information scheme

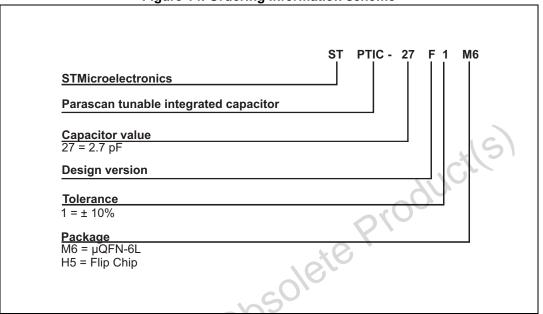


Table 6. Ordering information

	Part Number	Marking	Weight	Base Qty	Delivery Mode
	STPTIC-12F1M6	12	4.8 mg	3000	Tape and reel
	STPTIC-27F1M6	27	4.8 mg	3000	Tape and reel
	STPTIC-33F1M6	33	4.8 mg	3000	Tape and reel
	STPTIC-39F1M6	39	4.8 mg	3000	Tape and reel
	STPTIC-47F1M6	47	4.8 mg	3000	Tape and reel
7/6	STPTIC-56F1M6	56	4.8 mg	3000	Tape and reel
1250.	STPTIC-68F1M6	68	4.8 mg	3000	Tape and reel
Ob	STPTIC-82F1M6	82	4.8 mg	3000	Tape and reel
	STPTIC-12G1H5	TBD	0.7 mg	15000	Tape and reel
	STPTIC-27G1H5	l1x	0.7 mg	15000	Tape and reel
	STPTIC-33G1H5	l3x	0.7 mg	15000	Tape and reel
	STPTIC-39G1H5	I2x	0.7 mg	15000	Tape and reel
	STPTIC-47G1H5	l5x	0.7 mg	15000	Tape and reel
	STPTIC-56G1H5	I4x	0.7 mg	15000	Tape and reel
	STPTIC-68G1H5	l7x	0.7 mg	15000	Tape and reel
	STPTIC-82G1H5	l6x	0.7 mg	15000	Tape and reel

Revision history STPTIC

6 Revision history

Table 7. Document revision history

	Date	Revision	Changes
	02-Nov-2012	1	Initial release.
	03-Jul-2013	2	Removed 6-pad 650 x 1000 Flip-Chip package.
	10-Jan-2014	3	updated: Features, Table 2, Table 4, Table 6 and added new Figure 4.
	13-Feb-2014	4	Updated Applications.
Obsole	te Pro	ductl	Figure 4. Updated Applications.

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